NSN 5962-01-341-5886

Memory Microcircuit - Page 1 of 2

20 printed circuit



View Online at https://aerobasegroup.com/nsn/5962-01-341-5886

Body Length:	
1.060 inches	
Body Width:	
0.310 inches	
Body Height:	
0.185 inches	
Maximum Power Dissipation Rating:	
320.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Ultraviolet erasable and programmed and monolithic and burn in and bidirectional and tested to mil-std-883	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Complementary-metal oxide-semiconductor logic	
Input Circuit Pattern:	
18 input	
Case Outline Source And Designator:	
D-8 mil-m-38510	
Current Rating Per Characteristic:	
80.00 milliamperes reverse current, dc absolute	
Terminal Surface Treatment:	
Solder	
Product Name:	
300 gate cmos uv epid	
Voltage Rating And Type Per Characteristic:	
7.0 volts power source	
Capitance Rating Per Characteristic:	
12.00 input picofarads	
Time Rating Per Chacteristic:	
500.00 nanoseconds fall	
Memory Device Type:	
Pal	
Test Data Document:	
96906-mil-std 883 standard (includes industry or association standards, individual manufactureer standards, e	ic.).
Terminal Type And Quantity:	
20 printed aircuit	

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Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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